1200-V Direct WGB Diode

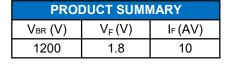
Key Features:

- SiC performance
- Easy paralleling
- High current carrying capability
- Very low junction capacitance
- Highly stable VF and QRR at elevated temperatures

Typical Applications:

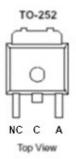
- Soft switching topologies
- Secondary side rectification











ABSOLUTE MAXIMUM RATINGS ($T_A = 25^{\circ}C$ UNLESS OTHERWISE NOTED)				
Parameter		Symbol	Limit	Units
Cathode-Anode Voltage		V_{BR}	1200	V
Diode Forward Current ^a	T _C =25°C	I _{F(AV)}	10	А
Single Pulse Forward Current ^b	T _C =25°C	I _{FSM}	50	А
Joule Integral		i ² t	12	A²⋅s
Storage Temperature Range		T _{stg}	-55 to 150	°C
Operating Junction Temperature		Τ _J	-40 to 120	°C

THERMAL RESISTANCE RATINGS				
Parameter	Symbol	Maximum	Units	
Maximum Junction-to-Ambient ^a	R _{θJA}	40	°C/W	
Maximum Junction-to-Case	R _{eJC}	3	C/W	

Notes

- a. Surface Mounted on 1" x 1" FR4 Board.
- Pulse width limited by maximum junction temperature b.

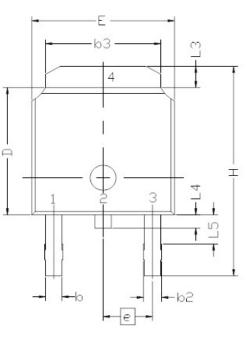
Electrical Characteristics

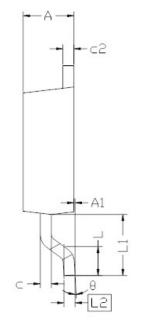
Parameter	Symbol	Test Conditions	Min	Тур	Max	Unit
		Static	-			
Forward Voltage ^a	V _F	I _F = 10 A		1.8		v
	VF	I _F = 10 A, T _J = 120°C	= 120°C 1.84			7
Repetitive Peak Reverse Voltage	V _{RRM}	$T_{\rm J}$ = -40°C to 120°C	1200			V
Junction Capacitance	CJ	V_R = 200 V, V_{sine} = 0.6 V_{eff} , f = 100 kHz		6.3		pF
	V _R = 1200 V	V _R = 1200 V			2	uA
Reverse Leakage Current	I _R	V _R = 1200 V, T _J = 120°C	-60		10	uA
		Dynamic ^b				•
Reverse Recovery Time	T _{rr}			80		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 100 A/us, T _J = 25°C		157		nC
Peak Recovery Current	I _{RRM}	1j - 20 0		3.3		А
Reverse Recovery Time	T _{rr}	I _F = 10 A, dI/dt = 100 A/us,		75		ns
Reverse Recovery Charge	Q _{rr}	$T_{\rm F} = 10$ A, di/dt = 100 A/ds, T_{\rm J} = 120°C		127		nC
Peak Recovery Current	I _{RRM}	1, 120 0		2.8		A
Reverse Recovery Time	T _{rr}	I _F = 10 A, dI/dt = 500 A/us,		32		ns
Reverse Recovery Charge	Q _{rr}	$T_F = 10 \text{ A}, \text{ di/dt} = 500 \text{ A/ds}, T_J = 25^{\circ}\text{C}$		215		nC
Peak Recovery Current	I _{RRM}	1, 200		11.2		A
Reverse Recovery Time	T _{rr}	I = 10 A d / dt = 500 A / uc		32		ns
Reverse Recovery Charge	Q _{rr}	I _F = 10 A, dl/dt = 500 A/us, T _{.I} = 120°C		193		nC
Peak Recovery Current	I _{RRM}	1, 120 0		9.9		А

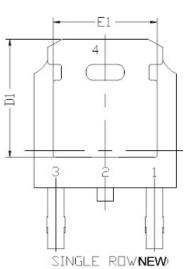
Notes

- a. Pulse test: PW <= 300us duty cycle <= 2%.
- b. Guaranteed by design, not subject to production testing.

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OVADDI	DIMENS:	IONAL F	REQMIS		
SYMBOL	MIN	NDM	MAX		
E	6.40	6.60	6.731		
L	1.40	1.52	1.77		
L1	2	.743 R	ĒF		
L2	0.	508 BS	C		
L3	0.89		1.27		
L4	0.64		1.01		
L5					
D	6.00	6.10	6.223		
Н	9.40	10.00	10.40		
b	0.64	0.76	0.88		
b2	0.77	0.84	1.14		
b3	5.21	5.34	5.46		
е	2.286 BSC				
A	2.20	2.30	2.38		
A1	0		0.127		
C	0.45	0.50	0,60		
c2	0.45	0,50	0,58		
D1	5.30				
E1	4.40				
θ	0°		10°		

Note:

- 1. All Dimension Are In mm.
- 2. Package Body Sizes Exclude Mold Flash, Protrusion Or Gate Burrs. Mold Flash, Protrusion Or Gate Burrs Shall Not Exceed 0.10 mm Per Side.

Package Information

3. Package Body Sizes Determined At The Outermost Extremes Of The Plastic Body Exclusive Of Mold Flash, Gate Burrs And Interlead Flash, But Including Any Mismatch Between The Top And Bottom Of The Plastic Body.